

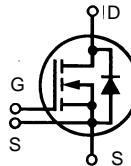
# HiPerFET™ Power MOSFETs Single Die MOSFET

N-Channel Enhancement Mode  
Avalanche Rated, High dv/dt, Low  $t_{rr}$

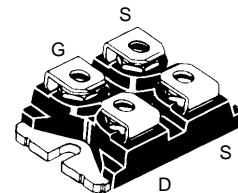
Preliminary data

## IXFN 60N60

$V_{DSS}$  = 600 V  
 $I_{D25}$  = 60 A  
 $R_{DS(on)}$  = 75 mΩ



miniBLOC, SOT-227 B (IXFN)  
 E153432



G = Gate      D = Drain  
S = Source      TAB = Drain

Either Source terminal at miniBLOC can be used as Main or Kelvin Source

Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	600	V	
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 1 \text{ M}\Omega$	600	V	
$V_{GS}$	Continuous	$\pm 20$	V	
$V_{GSM}$	Transient	$\pm 30$	V	
$I_{D25}$	$T_c = 25^\circ\text{C}$ , Chip capability	60	A	
$I_{DM}$	$T_c = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$	240	A	
$I_{AR}$	$T_c = 25^\circ\text{C}$	60	A	
$E_{AR}$	$T_c = 25^\circ\text{C}$	64	mJ	
$E_{AS}$	$T_c = 25^\circ\text{C}$	4	J	
$dv/dt$	$I_s \leq I_{DM}$ , $di/dt \leq 100 \text{ A}/\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$ , $R_G = 2 \Omega$	5	V/ns	
$P_D$	$T_c = 25^\circ\text{C}$	700	W	
$T_J$		-55 ... +150	$^\circ\text{C}$	
$T_{JM}$		150	$^\circ\text{C}$	
$T_{stg}$		-55 ... +150	$^\circ\text{C}$	
$V_{ISOL}$	50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	2500 3000	V~	
$M_d$	Mounting torque Terminal connection torque	1.5/13	Nm/lb.in.	
<b>Weight</b>		30	g	

Symbol	Test Conditions	Characteristic Values		
		( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$V_{DSS}$	$V_{GS} = 0 \text{ V}$ , $I_D = 3 \text{ mA}$	600		V
$V_{GH(\text{th})}$	$V_{DS} = V_{GS}$ , $I_D = 8 \text{ mA}$	2		4.5 V
$I_{GSS}$	$V_{GS} = \pm 20 \text{ V}_{DC}$ , $V_{DS} = 0$			$\pm 200 \text{ nA}$
$I_{DSS}$	$V_{DS} = V_{DSS}$ $V_{GS} = 0 \text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$		100 $\mu\text{A}$ 2 mA
$R_{DS(on)}$	$V_{GS} = 10 \text{ V}$ , $I_D = 0.5 \cdot I_{D25}$ Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $d \leq 2 \%$			75 mΩ

## Applications

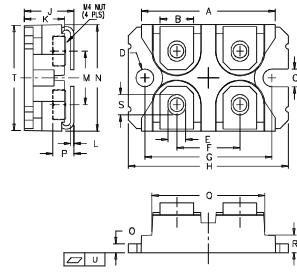
- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- Temperature and lighting controls

## Advantages

- Easy to mount
- Space savings
- High power density

Symbol	Test Conditions	Characteristic Values			
		( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	min.	typ.	max.
$g_{fs}$	$V_{DS} = 15 \text{ V}; I_D = 0.5 \cdot I_{D25}$ , pulse test	40	60	S	
$C_{iss}$		15000		pF	
$C_{oss}$		1600		pF	
		360		pF	
$t_{d(on)}$		43		ns	
$t_r$		52		ns	
$t_{d(off)}$		110		ns	
$t_f$		26		ns	
$Q_{g(on)}$		380		nC	
$Q_{gs}$		78		nC	
$Q_{gd}$		190		nC	
$R_{thJC}$			0.18	K/W	
$R_{thCK}$			0.05	K/W	

## miniBLOC, SOT-227 B



M4 screws (4x) supplied

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	38.00	38.23	1.496	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.76	0.84	0.030	0.033
M	12.60	12.85	0.496	0.506
N	25.15	25.42	0.990	1.001
O	1.98	2.13	0.078	0.084
P	4.95	5.97	0.195	0.235
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.174
S	4.72	4.85	0.186	0.191
T	24.59	25.07	0.968	0.987
U	-0.05	0.1	-0.002	0.004

## Source-Drain Diode

## Characteristic Values

 $(T_J = 25^\circ\text{C}$ , unless otherwise specified)

Symbol	Test Conditions	Characteristic Values		
		min.	typ.	max.
$I_s$	$V_{GS} = 0 \text{ V}$		60	A
$I_{SM}$	Repetitive; pulse width limited by $T_{JM}$		240	A
$V_{SD}$	$I_F = I_s, V_{GS} = 0 \text{ V},$ Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $d \leq 2 \%$		1.3	V
$t_{rr}$	$I_F = 25 \text{ A}, -di/dt = 100 \text{ A}/\mu\text{s}, V_R = 100 \text{ V}$		250	ns
$Q_{RM}$		1.5		$\mu\text{C}$
$I_{RM}$		10		A



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